

# SEMICONDUCTOR TECHNICAL DATA

### **KTC4379**

### EPITAXIAL PLANAR NPN TRANSISTOR

## POWER AMPLIFIER APPLICATIONS. POWER SWITCHING APPLICATIONS.

### **FEATURES**

- · Low Saturation Voltage
  - :  $V_{CE(sat)} = 0.5V(Max.) (I_C = 1A)$
- · High Speed Switching Time :  $t_{stg}$ =1.0  $\mu$ S(Typ.)
- ·  $P_C=1 \sim 2W$  (Mounted on Ceramic Substrate)
- · Small Flat Package.
- · Complementary to KTA1666.
- · Suffix  $\underline{\mathbf{U}}$ : Qualified to AEC-Q101.
  - ex) KTC4379-Y-RTF/H<u>U</u>

### MAXIMUM RATING (Ta=25℃)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V <sub>CBO</sub>	50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	50	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	V
Collector Current	$I_{C}$	2	A
Base Current	$I_{\mathrm{B}}$	0.4	A
Collector Power Dissipation	P <sub>C</sub>	500	mW
Conector Fower Dissipation	P <sub>C</sub> *	1	W
Junction Temperature	T <sub>j</sub>	150	$^{\circ}$
Storage Temperature Range	$T_{stg}$	-55~150	$^{\circ}$

P<sub>C</sub>\*: KTC4379 mounted on ceramic substrate (250mm<sup>2</sup>x0.8t)

# DIM MILLIMETERS A 4.70 MAX B 2.50 ±0.20 C 1.70 MAX D 0.45+0.15/-0.10 E 4.25 MAX F 1.50±0.10 G 0.40 TYP H 1.75 MAX J 0.75 MIN K 0.5+0.10/-0.05 L 1.40 ± 0.10 M 0.19 ± 0.10 N 0.47 ± 0.10 SOT-89

# Marking hFE Rank Lot No. Type Name

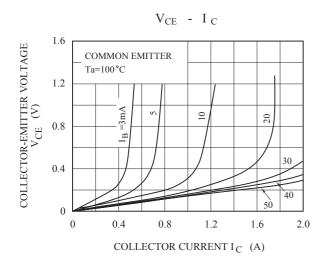
### ELECTRICAL CHARACTERISTICS (Ta=25°C)

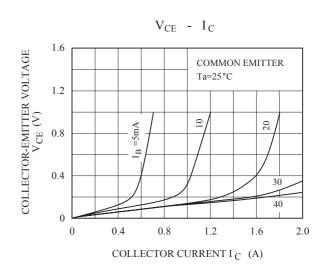
CHARA	CTERISTIC	SYMBOL	TEST CONDITION		TYP.	MAX.	UNIT
Collector Cut-off Current		$I_{CBO}$	$V_{CB} = 50V, I_{E} = 0$	-	-	0.1	μA
Emitter Cut-off Current		$I_{EBO}$	$V_{EB}=5V$ , $I_{C}=0$	-	-	0.1	$\mu$ A
Collector-Emitter Breakdown Voltage		V <sub>(BR)CEO</sub>	$I_{C}=10\text{mA},\ I_{B}=0$	50	-	-	V
DC Current Gain		h <sub>FE</sub> (1) (Note2)	V <sub>CE</sub> =2V, I <sub>C</sub> =0.5A (Note 1)	70	-	240	
		h <sub>FE</sub> (2)	V <sub>CE</sub> =2V, I <sub>C</sub> =1.5A (Note 1)	40	-	-	
Collector-Emitter Saturation Voltage		V <sub>CE(sat)</sub>	I <sub>C</sub> =1A, I <sub>B</sub> =0.05A (Note 1)	-	-	0.5	V
Base-Emitter Saturation Voltage		V <sub>BE(sat)</sub>	I <sub>C</sub> =1A, I <sub>B</sub> =0.05A (Note 1)	-	-	1.2	V
Transition Frequency		$f_T$	$V_{CE}=2V, I_{C}=0.5A$	-	120	-	MHz
Collector Output Capacitance		C <sub>ob</sub>	$V_{CB}=10V, I_{E}=0, f=1MHz$	-	30	-	pF
Switching Time	Turn-on Time	t <sub>on</sub>	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	-	0.1	-	
	Storage Time	t <sub>stg</sub>		-	1.0	-	μS
	Fall Time	$t_{\mathrm{f}}$		-	0.1	-	

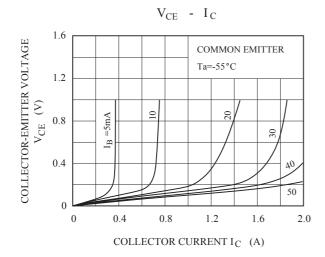
Note 1 : Pulse width  $\leq 300 \,\mu\text{S}$ , Duty Cycle  $\leq 1\%$ 

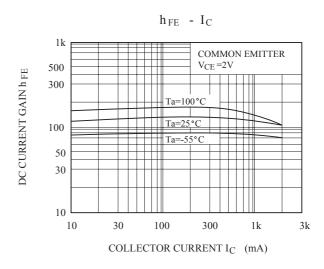
Note 2:  $h_{FE}(1)$  Classification 0:70 ~ 140, Y:120 ~ 240

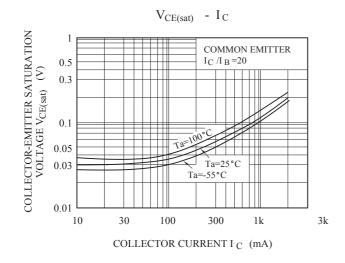
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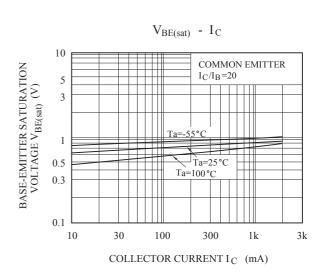




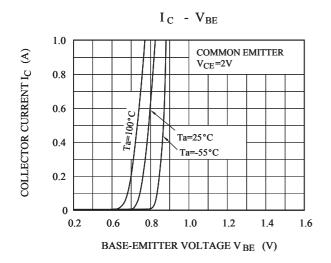


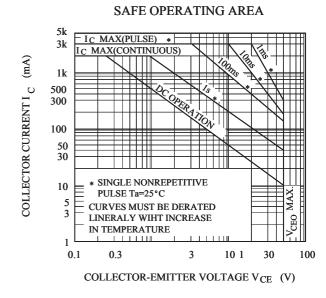


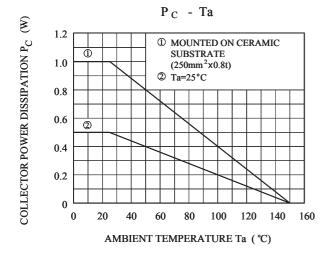




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